
	<h2>SI7478DP-T1-GE3</h2>
	<p>Hersteller-Teilenummer: SI7478DP-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 60V 15A PPAK SO-8</p> <p>Datenblätter:  SI7478DP-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 19838 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI7478DP-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 60V 15A PPAK SO-8
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	19838 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	PowerPAK® SO-8
Supplier Device-Gehäuse	PowerPAK® SO-8
Verlustleistung (max)	1.9W (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	15A (Ta)
Rds On (Max) @ Id, Vgs	7.5 mOhm @ 20A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	160nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	-
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Original-Reel®

























SI7478DP-T1-GE3 ist neu im Original, Suche SI7478DP-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI7478DP-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI7478DP-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI7483ADP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 30V 14A PPAK SO-8</p>	 <p>SI7483ADP-T1-E3 Vishay / Siliconix MOSFET P-CH 30V 14A PPAK SO-8</p>	 <p>SI7478DP-T1-E3 Vishay / Siliconix MOSFET N-CH 60V 15A PPAK SO-8</p>	 <p>SI7478DP SI SI7478DP SI</p>
 <p>SI7476DP-T1-GE3 Vishay / Siliconix MOSFET N-CH 40V 15A PPAK SO-8</p>	 <p>SI7483ADP-T1-GE3 Vishay / Siliconix MOSFET P-CH 30V 14A PPAK SO-8</p>	 <p>SI7478DP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 60V 15A PPAK SO-8</p>	 <p>SI7483ADP SI SI7483ADP SI</p>

heiße Teile

Mehr

 SI7461DP-T1-GE3	 SI7461DP-T1-E3	 SI7462DP-T1-E3	 SI7462DP-T1-E3	 SI7462DP-T1-GE3
 SI7462DP-T1-GE3	 SI7463ADP-T1-GE3	 SI7463ADP-T1-GE3	 SI7463DP-T1-GE3	 SI7463DP-T1-GE3
 SI7464DP-T1-E3	 SI7464DP-T1-E3	 SI7464DP-T1-GE3	 SI7464DP-T1-GE3	 SI7465DP-T1-E3
 SI7465DP-T1-E3	 SI7465DP-T1-GE3	 SI7465DP-T1-GE3	 SI7470DP-T1-GE3	 SI7476DP-T1-GE3
 SI7476DP-T1-GE3	 SI7478DP	 SI7478DP-T1-E3	 SI7478DP-T1-E3	 SI7478DP-T1-GE3
 SI7483ADP	 SI7483ADP-T1-E3	 SI7483ADP-T1-E3	 SI7483ADP-T1-GE3	 SI7483ADP-T1-GE3
 SI7483DP-T1	 SI7483DP-T1-E3	 SI7483DP-T1-GE3	 SI7485DP-T1-E3	 SI7485DP-T1-E3
 SI7485DP-T1-GE3	 SI7485DP-T1-GE3	 SI7489DP	 SI7489DP-T1-GE3	 SI7489DP-T1-GE3
 SI7491DP	 SI7491DP-T1-GE3	 SI7491DP-T1-GE3	 SI7501DN-T1-E3	 SI7501DN-T1-E3
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Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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